



40V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(ON)}	Ι _D T _A = +25°C		
40V	0.05Ω @ V _{GS} = 10V	7A		

Description

This new generation MOSFET has been designed to minimize the onstate resistance ($R_{DS(ON)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- DC-DC Converters
- Audio Output Stages
- Relay and Solenoid driving
- Motor Control

Features

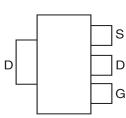
- Low On-Resistance
- Fast Switching Speed
- Low Threshold
- Low Gate Drive
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Available

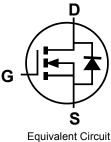
Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper lead frame. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (approximate)

SOT223

Top View





Pin Out - Top View

Ordering Information (Note 4 & 5)

	A		
Part Number	Compliance	Case	Packaging
ZXMN4A06GQTA	Automotive	SOT223	1,000/Tape & Reel
ZXMN4A06GQTC	Automotive	SOT223	4,000/Tape & Reel

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

 See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

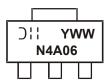
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_grade_definitions/.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

Note:



):! = Manufacturer's Marking
N4A06 = Marking Code
YWW = Date Code Marking
Y = Year (ex: 3 = 2013)
WW = Week (01 - 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage		V _{DSS}	40	V	
Gate-Source Voltage			V _{GS}	±20	V
		(Note 7)		7	
Continuous Drain Current	V _{GS} = 10V	T _A = +70°C (Note 7)	ID	5.6	А
		(Note 6)		5	
Pulsed Drain Current	V _{GS} = 10V	(Note 8)	I _{DM}	22	A
Continuous Source Current ((Body diode)	(Note 7)	IS	5.4	A
Pulsed Source Current (Body diode) (Note 8)		I _{SM}	22	А	

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation Linear Derating Factor	(Note 6)	5	2 16	W	
	(Note 7)	PD	3.9 31	mW/°C	
Thermal Resistance, Junction to Ambient	(Note 6)	D	62.5	°C/W	
	(Note 7)	R _{θJA}	32.2		
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BV _{DSS}	40	_	_	V	I _D = 250μA, V _{GS} = 0V	
Zero Gate Voltage Drain Current	I _{DSS}	_		1	μA	V _{DS} = 40V, V _{GS} = 0V	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	V_{GS} = ±20V, V_{DS} = 0V	
ON CHARACTERISTICS							
Gate Threshold Voltage	V _{GS(th)}	1		_	V	I_D = 250µA, V_{DS} = V_{GS}	
Static Drain-Source On-Resistance (Note 9)	D			0.05	Ω	V _{GS} = 10V, I _D = 4.5A	
	R _{DS(ON)}			0.075		V _{GS} = 4.5V, I _D = 3.2A	
Forward Transconductance (Notes 11)	g fs	_	8.7	_	S	V _{DS} = 15V, I _D = 2.5A	
Diode Forward Voltage (Note 9)	V _{SD}	_	0.8	0.95	V	I_{S} = 2.5A, V_{GS} = 0V, T_{J} = +25°C	
Reverse recovery time (Note 11)	t _{rr}		14.5	—	ns	$I_F = 2.5A$, di/dt = 100A/µs, $T_J = +25^{\circ}C$	
Reverse recovery charge (Note 11)	Qrr	_	7.8	—	nC		
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	C _{iss}	_	746	_	pF	V _{DS} = 40V, V _{GS} = 0V f = 1MHz	
Output Capacitance	C _{oss}	_	93	_	pF		
Reverse Transfer Capacitance	C _{rss}	_	60	—	pF		
Total Gate Charge (Note 11)	Qg	_	19	_	nC	V_{DS} = 30V, V_{GS} = 10V, I_D = 2.5A (refer to test circuit)	
Gate-Source Charge (Note 11)	Q _{gs}	_	2.3	_	nC		
Gate-Drain Charge (Note 11)	Q _{gd}	_	4.1	_	nC		
Turn-On Delay Time (Note 11)	t _{D(on)}	_	3.4	—	ns	$V_{DD} = 30V, V_{GS} = 10V$ $I_D = 2.5A, R_G \cong 6\Omega$ (refer to test circuit)	
Turn-On Rise Time (Note 11)	tr	_	2.8	—	ns		
Turn-Off Delay Time (Note 11)	t _{D(off)}	_	20	_	ns		
Turn-Off Fall Time (Note 11)	t _f		7.7	_	ns		

Notes:

6. For a device surface mounted on 25mm x 25mm FR-4 PCB with high coverage of single sided 1oz copper, in still air conditions.
7. For a device surface mounted on FR-4 PCB measured at t≤5 secs.
8. Repetitive rating 25mm x 25mm FR4 PCB, D = 0.05, pulse width 10µs - pulse width limited by maximum junction temperature.

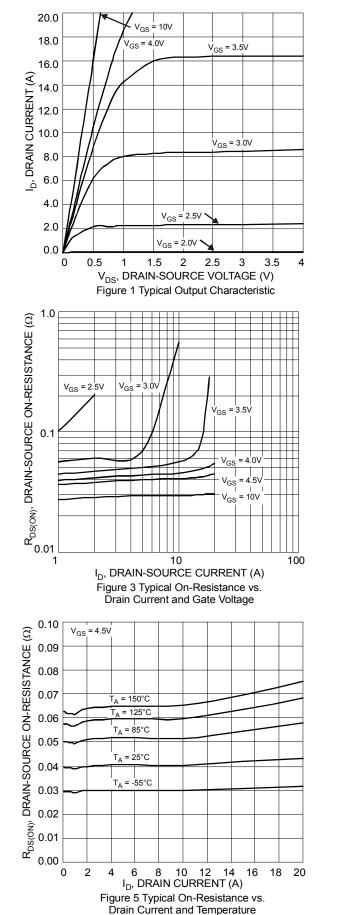
9. Measured under pulsed conditions. Pulse width \leq 300µs; duty cycle \leq 2%.

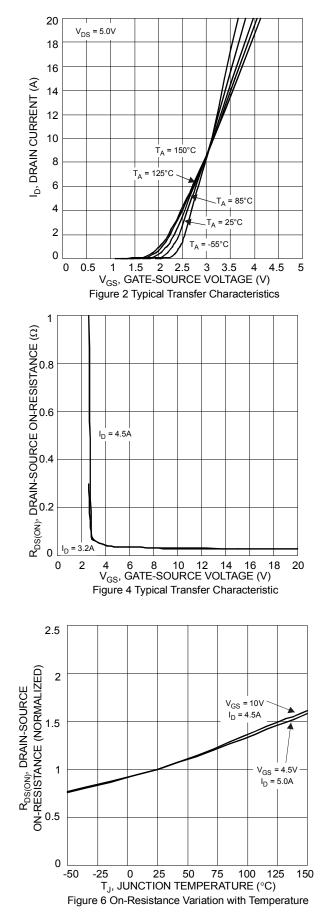
10. Switching characteristics are independent of operating junction temperatures.

11. For design aid only, not subject to production testing.

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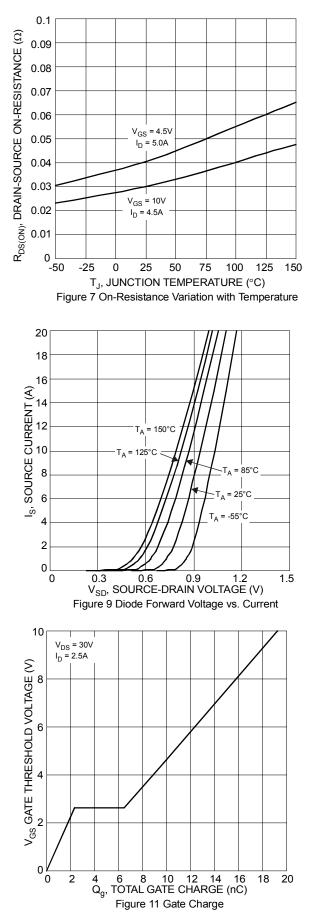


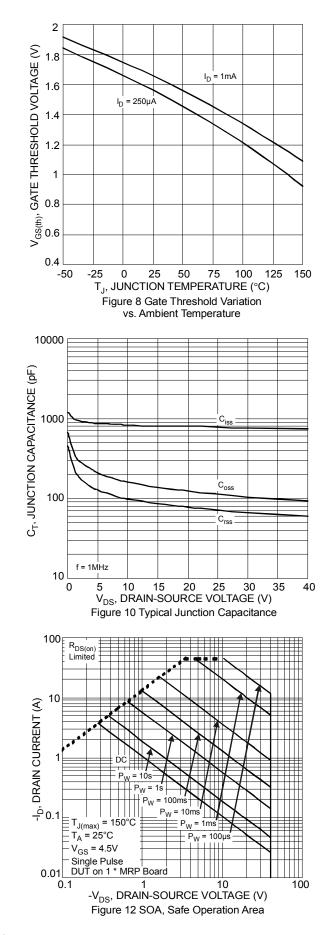




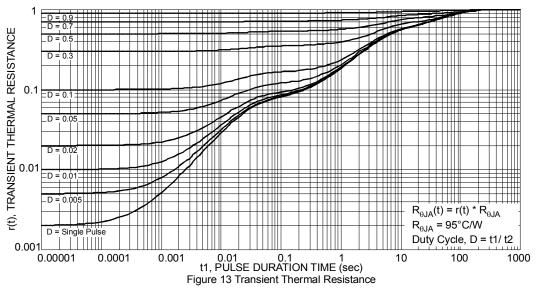
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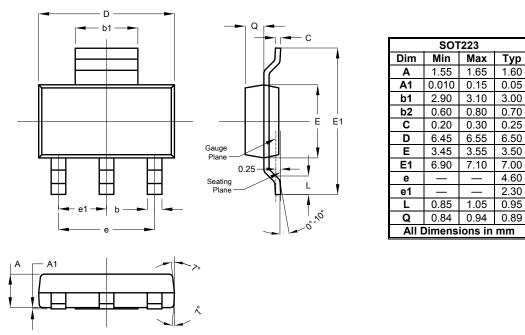






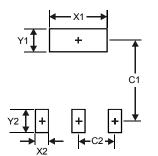
Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for latest version.



Dimensions	Value (in mm)
X1	3.3
X2	1.2
Y1	1.6
Y2	1.6
C1	6.4
C2	2.3

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